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SEMICONDUCTOR®

FDMB3900AN

Dual N-Channel PowerTrench MOSFET 25 V, 7.0 A, 23 m Ω

Features

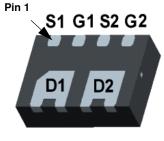
- Max $r_{DS(on)} = 23 \text{ m}\Omega$ at $V_{GS} = 10 \text{ V}$, $I_D = 7.0 \text{ A}$
- Max $r_{DS(on)}$ = 33 m Ω at V_{GS} = 4.5 V, I_D = 5.5 A
- Fast switching speed
- Low gate charge
- High performance trench technology for extremely low r_{DS(on)}
- High power and current handling capability
- RoHS Compliant



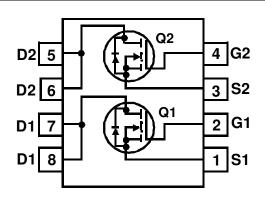
General Description

These N-Channel Logic Level MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench® process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

These devices are well suited for low voltage and battery powered applications where the low in-line power loss and fast switching are required.







MOSFET Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Param		Ratings	Units	
V_{DS}	Drain to Source Voltage			25	V
V_{GS}	Gate to Source Voltage			±20	V
1	Drain Current -Continuous	T _A = 25 °C	(Note 1a)	7.0	۸
'D	-Pulsed			28	Α
В	Power Dissipation	T _A = 25 °C	(Note 1a)	1.6	W
P_D	Power Dissipation	T _A = 25 °C	(Note 1b)	0.8	VV
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	80	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	165	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
3900	FDMB3900AN	MicroFET 3X1.9	7 "	8 mm	3000 units

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	25			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		17		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 20 V, V _{GS} = 0 V			1	μА
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	1.0	2.0	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I _D = 250 μA, referenced to 25 °C		-6		mV/°C
	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 7.0 \text{ A}$		19	23	
r ·		$V_{GS} = 4.5 \text{ V}, I_D = 5.5 \text{ A}$		26	33	mΩ
r _{DS(on)} Static Drain to Source On Resistance		$V_{GS} = 10 \text{ V}, I_D = 7.0 \text{ A}$ $T_J = 125 \text{ °C}$		26	32	11122
9 _{FS}	Forward Transconductance	$V_{DS} = 5 \text{ V}, I_{D} = 7.0 \text{ A}$		27		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 10 V V 0 V	650	890	рF
Coss	Output Capacitance	$V_{DS} = 13 \text{ V}, V_{GS} = 0 \text{ V}$ f = 1 MHz	151	200	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1101112	141	215	pF
R_g	Gate Resistance		0.8		Ω

Switching Characteristics

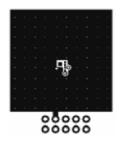
t _{d(on)}	Turn-On Delay Time		6	12	ns
t _r	Rise Time	V _{DD} = 13 V, I _D = 7.0 A	3	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$	15	26	ns
t _f	Fall Time		3	10	ns
0	Total Gate Charge	V _{GS} = 0 V to 10 V	11	17	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0 \text{ V to 5 V}$ $V_{DD} = 13 \text{ V}$	7	10	nC
Q_{gs}	Gate to Source Charge	I _D = 7.0 A	2.0		nC
Q_{gd}	Gate to Drain "Miller" Charge		3.0		nC

Drain-Source Diode Characteristics

V	Von Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = 1.25 \text{ A}$ (Note 2)		0.8	1.2	V
v SD		$V_{GS} = 0 \text{ V}, I_S = 7.0 \text{ A}$ (Note 2)		0.9	1.2	
t _{rr}	Reverse Recovery Time	- I _F = 7.0 A, di/dt = 100 A/μs		14	24	ns
Q _{rr}	Reverse Recovery Charge			3	10	nC

NOTES

⁻ R_{0JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{θCA} is determined by the user's board design.



a. 80 °C/W when mounted on a 1 in² pad of 2 oz copper



b.165 °C/W when mounted on a minimum pad of 2 oz copper

2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.

Typical Characteristics T_J = 25°C unless otherwise noted

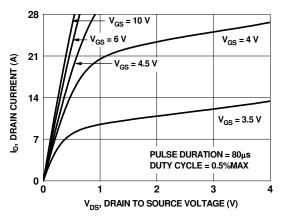


Figure 1. On-Region Characteristics

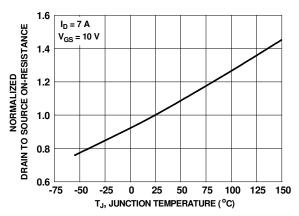


Figure 3. Normalized On-Resistance vs Junction Temperature

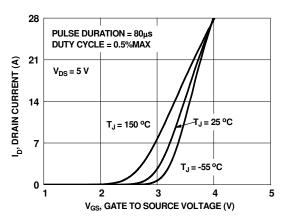


Figure 5. Transfer Characteristics

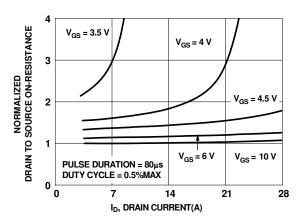


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

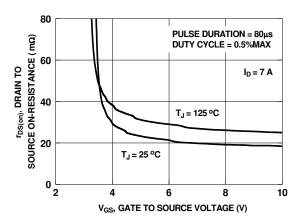


Figure 4. On-Resistance vs Gate to Source Voltage

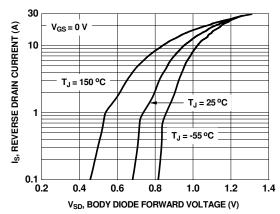


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics T_J = 25°C unless otherwise noted

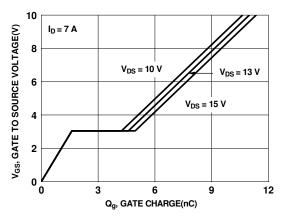


Figure 7. Gate Charge Characteristics

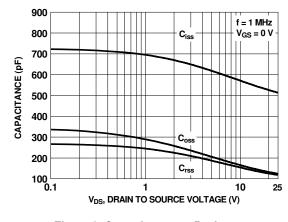


Figure 8. Capacitance vs Drain to Source Voltage

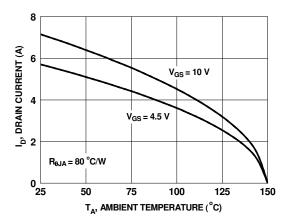


Figure 9. Maximum Continuous Drain Current vs Ambient Temperature

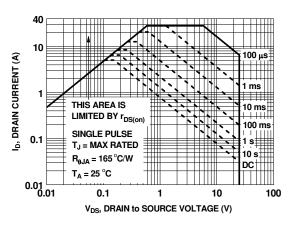


Figure 10. Forward Bias Safe Operating Area

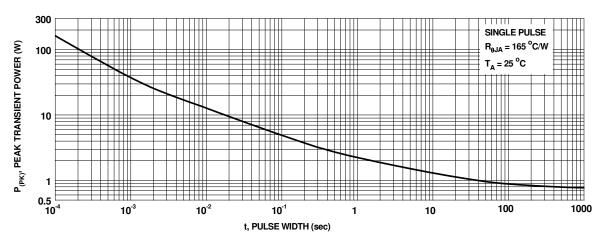


Figure 11. Single Pulse Maximum Power Dissipation

Typical Characteristics T_J = 25°C unless otherwise noted

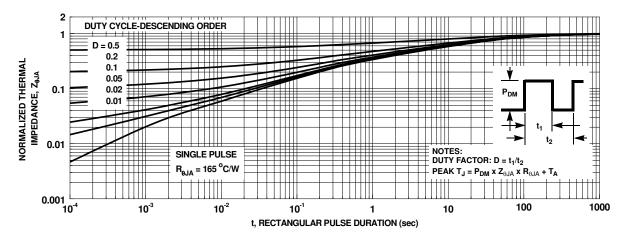
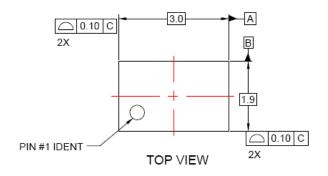
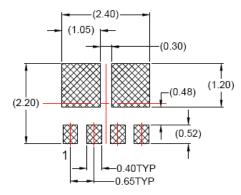


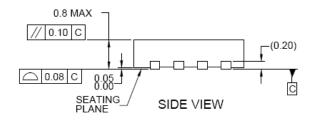
Figure 12. Junction-to-Ambient Transient Thermal Response Curve

Dimensional Outline and Pad Layout



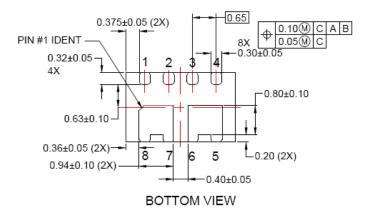


RECOMMENDED LAND PATTERN



NOTES:

- (A) DOES NOT FULLY CONFORM TO JEDED REGISTRATION MO-229.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.







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